



Many-particle theory of all-optical polarization switching in semiconductor quantum wells

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All optical polarization switch: developed at Univ. Iowa (2002)

Characteristics:

- ◆ ultrafast (sub-ps)
- ◆ high contrast ratio (200:1)
- ◆ not yet room temperature ($T=100$)
- ◆ planar fabrication
- ◆ isotropic material

Operation:

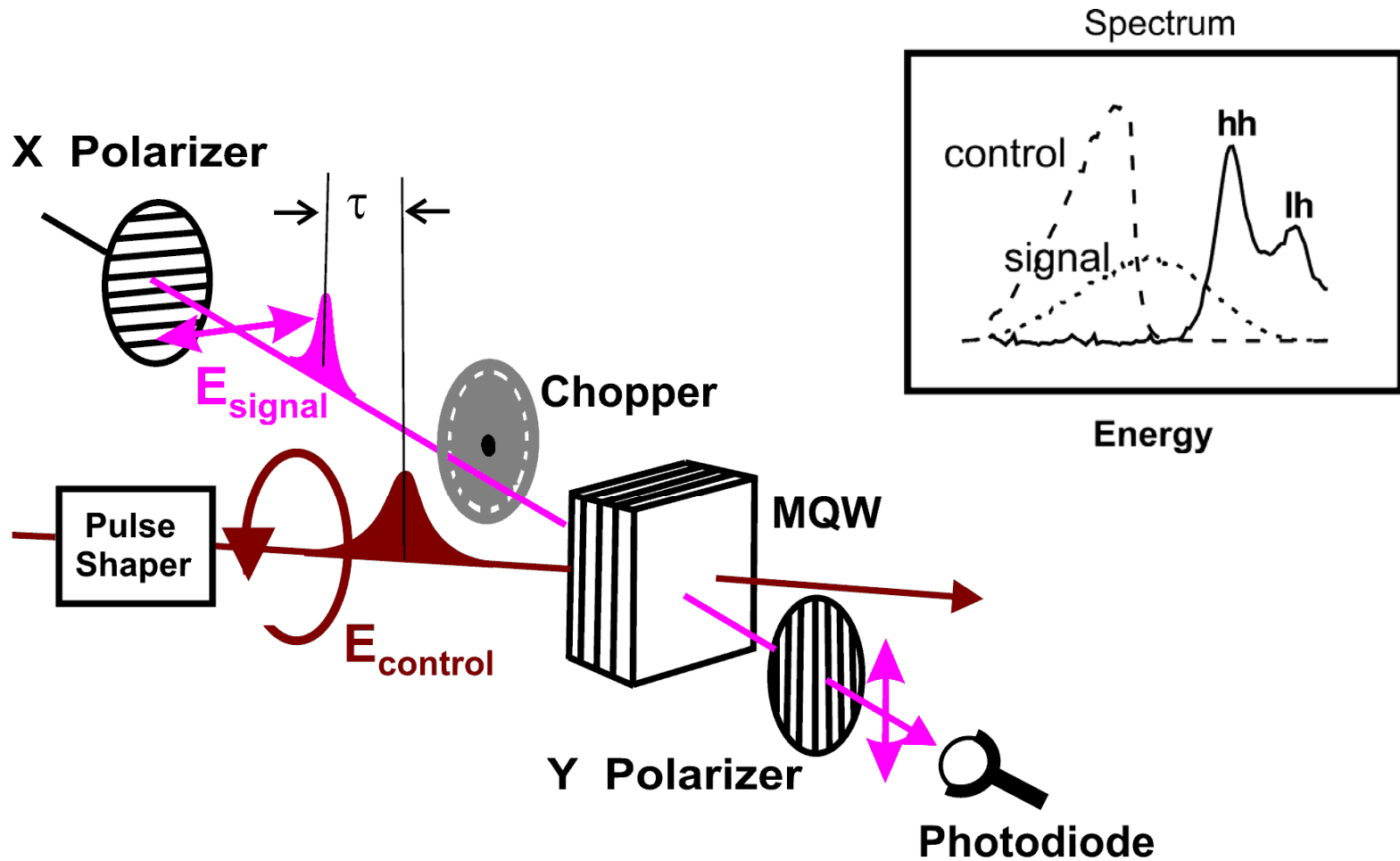
- ◆ based on selective excitation of spin states

Theoretical issues:

- ◆ understanding of switching process with predictive theory
- ◆ identification of main many-particle process
- ◆ study of parametric dependencies of switch
- ◆ prediction of possible future optimization

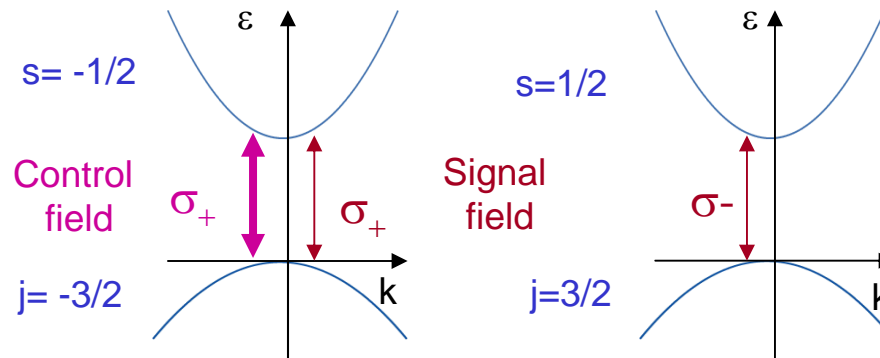


Experimental Scheme





Band structure & selection rules



X-polarized signal field: equal-strength σ_+ and σ_- transition (no rotation)

- “+” polarized control field \Rightarrow unequal σ_+ and σ_- transitions
- \Rightarrow elliptical polarization of signal output



Time-integrated signal

